Testing Services™	Document Annex A_Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RCZ31CW			
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	April 05-08, 2010	RTS-2068-1004-46	L6ARCZ30C	W

Annex A: Measurement data and plots

A.1 Spectrum analyser plots: CDMA, CW and 80%AM ignals

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0 Hz Span CDMA Full Rate (835MHz)

Attayi		Dates of T April	est 05-08,	2010	Report No RTS-206	58-1004-4	6	FCC ID L6ARCZ30C	W
	5.824 Ref 27	1 16 08 n	A	tt 68 d8	RBN 3 11 - UBN 30 1 SNT 8 m	lz Narke Hz	r 1 [T1] 16.87 5.824000	dBa SELECT MARKER	
	50							я РЕАК	
CAL	10							CENTER - MKR FREQ	
SETUP	-10							REF LEVEL - MKR LUL	
HOUPY	-28							NEXT PEAK	
							- 40	NEXT PEAK RIGHT	1
	-58							NEXT PEAK LEFT	1
2	-60							SEARCH LIMITS 0	
	Center	PUR NET	ER		100 Jus."	2 seal	SCREET	HKR->TRACE	
6		-	30		76	76	16	PREV	NEXT
0			20)()(70)(PREV	NEXT

0 Hz Span CDMA 1/8 th (835MHz)

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0 Hz Span CW Plot (835MHz)



0 Hz Span 80% AM Plot (835MHz)

oud Attayi	Dates of Test April 05-08,	2010	Report No RTS-20	58-1004-46	FCC ID L6ARCZ3	0CW
ST ST	NUMBER 1 1.54 m Ref 27 dBa		itt 59 dB	RBN 3 NHz = VBN 30 kHz SNT 2.5 ms	Nerker 1 [T1] 16.63 dBa 1.540000 as	SELECT MARKER
THE CAL						PEAK CENTER = MKR FREQ
DKG-K- 60201 2008-41	-3					REF LEUEL = MKR LUL
HOOT	*				301	NEXT PEAK
Les la	•					NEXT PEAK LEFT SEARCH
L'AS	Center 1.7 SPECTRUN PUR	32 CHz	25		SCREEN B	LIMITS O
)(PREV

0 Hz Span CDMA Full Rate (1732 MHz)



0 Hz Span CDMA 1/8 th (1732 MHz)

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0 Hz Span CW Plot (1732 MHz)

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0 Hz Span 80% AM Plot (1732 MHz)

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0 Hz Span CDMA Full Rate (1880 MHz)





0 Hz Span CDMA 1/8 th (1880 MHz)

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0 Hz Span CW Plot (1880 MHz)



0 Hz Span 80% AM Plot (1880 MHz)

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A.2 Dipole validation and probe modulation factor plots

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Author Data Daoud Attayi	Dates of Test April 05-08, 2010	Report No RTS-2068-1004-46	FCC ID L6ARCZ30C	W

Date/Time: 4/7/2010 12:00:12 PM

File Name: HAC_E_Dipole_CW835_20.00dBm.da4

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Program Name: HAC RF E Dipole

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 103.5 V/m; Power Drift = 0.021 dB

Maximum value of Total (measured) = 162.9 V/m



E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 163.6 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 103.5 V/m; Power Drift = 0.021 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
153.8 M4	160.3 M4	158.2 M4
Grid 4	Grid 5	Grid 6
85.8 M4	87.8 M4	85.2 M4
Grid 7	Grid 8	Grid 9



 $0 \, dB = 163.6 \, V/m$



Date/Time: 4/7/2010 10:49:55 AM

File Name: HAC_E_Dipole_CDMA835.da4

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Program Name: HAC RF E Dipole

Communication System: CDMA 800; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 73.2 V/m; Power Drift = -0.056 dB

Maximum value of Total (measured) = 115.0 V/m

E Scan - measurement distance from the probe sensor center to CD835



Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 115.5 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 73.2 V/m; Power Drift = -0.056 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1 Grid 2 Grid 3 108.4 M4 112.8 M4 112.1 M4 Grid 6 Grid 4 Grid 5 59.7 M4 59.2 M4 60.7 M4 Grid 7 Grid 8 Grid 9 109.4 M4 115.5 M4 113.5 M4



 $0 \, dB = 115.5 \, V/m$



Date/Time: 4/7/2010 11:10:34 AM

File Name: HAC_E_Dipole_CDMA835_one_eigth.da4

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Program Name: HAC RF E Dipole

Communication System: CDMA 800 1/8 th; Frequency: 835 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 26.4 V/m; Power Drift = -0.182 dB

Maximum value of Total (measured) = 52.8 V/m

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid:

dx=5mm, dy=5mm

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Maximum value of peak Total field = 53.1 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 26.4 V/m; Power Drift = -0.182 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
43.8 M4	45.4 M4	45.2 M4
Grid 4	Grid 5	Grid 6
25.2 M4	25.2 M4	21.8 M4
Grid 7	Grid 8	Grid 9
53.1 M4	48.6 M4	46.9 M4



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Daoud Attayi	April 05-08, 2010	RTS-2068-1004-46	L6ARCZ30C	W

Date/Time: 4/7/2010 11:22:39 AM

File Name: HAC_E_Dipole_CW835_PMF_CDMA.da4

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Program Name: HAC RF E Dipole

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 72.8 V/m; Power Drift = 0.000 dB

Maximum value of Total (measured) = 115.0 V/m

E Scan - measurement distance from the probe sensor center to CD835



Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 115.2 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 72.8 V/m; Power Drift = 0.000 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1 Grid 2 Grid 3 106.3 M4 111.4 M4 110.4 M4 Grid 4 Grid 5 Grid 6 58.8 M4 60.2 M4 58.5 M4 Grid 7 Grid 8 Grid 9 115.2 M4 113.2 M4 110.1 M4



 $^{0 \}text{ dB} = 115.2 \text{V/m}$

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Date/Time: 4/7/2010 11:39:18 AM

File Name: HAC_E_Dipole_AM835_PMF_CDMA.da4

DUT: HAC-Dipole 835 MHz; Type: D835V3; Program Name: HAC RF E Dipole

Communication System: AM 80%; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 45.6 V/m; Power Drift = 0.081 dB

Maximum value of Total (measured) = 72.1 V/m



E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 72.4 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 45.6 V/m; Power Drift = 0.081 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
67.0 M4	70.2 M4	69.9 M4
Grid 4	Grid 5	Grid 6
37.4 M4	38.4 M4	37.4 M4
Grid 7	Grid 8	Grid 9
68.8 M4	72.4 M4	71.4 M4



 $0 \, dB = 72.4 \, V/m$



Date/Time: 4/7/2010 12:34:36 PM

File Name: <u>HAC_E_Dipole_CDMA1732.da4</u>

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF E Dipole

Communication System: CDMA AWS 1700; Frequency: 1732.5 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 107.4 V/m; Power Drift = -0.042 dB

Maximum value of Total (measured) = 94.2 V/m

E Scan - measurement distance from the probe sensor center to CD1880



Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 97.0 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 107.4 V/m; Power Drift = -0.042 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
88.8 M3	91.7 M3	90.0 M3
Grid 4	Grid 5	Grid 6
66.5 M3	68.5 M3	66.4 M3
66.5 M3 Grid 7	68.5 M3 Grid 8	66.4 M3 Grid 9



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Date/Time: 4/7/2010 1:01:20 PM

File Name: <u>HAC_E_Dipole_CDMA1732_one_eigth_.da4</u>

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF E Dipole

Communication System: CDMA AWS 1700_1/8th; Frequency: 1732.5 MHz;Duty Cycle:

1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 38.6 V/m; Power Drift = 0.005 dB

Maximum value of Total (measured) = 36.3 V/m



E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 36.6 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 38.6 V/m; Power Drift = 0.005 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
33.9 M4	36.6 M4	34.4 M4
Grid 4	Grid 5	Grid 6
24.1 M4	28.2 M4	24.7 M4
Grid 7	Grid 8	Grid 9
35.3 M4	35.3 M4	34.1 M4



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Date/Time: 4/7/2010 12:48:46 PM

File Name: HAC_E_Dipole_CW1732_CDMA.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF E Dipole

Communication System: CW; Frequency: 1732 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 103.6 V/m; Power Drift = 0.138 dB Maximum value of Total (measured) = 91.8 V/m

E Scan - measurement distance from the probe sensor center to CD1880


Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 94.3 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 103.6 V/m; Power Drift = 0.138 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
86.7 M3	89.3 M3	88.7 M3
Grid 4	Grid 5	Grid 6
64.7 M3	66.8 M3	63.9 M3
Grid 7	Grid 8	Grid 9
86.8 M3	94.3 M3	94.0 M3



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Date/Time: 4/7/2010 12:54:49 PM

File Name: HAC_E_Dipole_AM1732_CDMA.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Program Name: HAC RF E Dipole

Communication System: AM 80%_1732; Frequency: 1732 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 65.8 V/m; Power Drift = 0.193 dB

Maximum value of Total (measured) = 59.1 V/m



E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 60.8 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 65.8 V/m; Power Drift = 0.193 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
55.2 M4	56.6 M4	55.8 M4
Grid 4	Grid 5	Grid 6
40.9 M4	41.8 M4	41.3 M4
Grid 7	Grid 8	Grid 9
56.0 M4	60.8 M4	60.7 M4



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Date/Time: 4/7/2010 2:29:31 PM

File Name: HAC_E_Dipole_CW1880_20.00dBm.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF E Dipole

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 145.3 V/m; Power Drift = -0.198 dB Maximum value of Total (measured) = 125.7 V/m



Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 127.6 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 145.3 V/m; Power Drift = -0.198 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
116.8 M2	123.1 M2	121.2 M2
Grid 4	Grid 5	Grid 6
83.5 M3	86.8 M3	84.5 M3
Grid 7	Grid 8	Grid 9
120.2 M2	127.6 M2	126.5 M2



 $^{0 \}text{ dB} = 127.6 \text{V/m}$



Date/Time: 4/7/2010 2:06:47 PM

File Name: HAC_E_Dipole_CDMA1880.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF E Dipole

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 97.3 V/m; Power Drift = 0.045 dB Maximum value of Total (measured) = 86.1 V/m



Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 87.5 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 97.3 V/m; Power Drift = 0.045 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1 Grid 2 Grid 3 80.4 M3 84.2 M3 83.8 M3 Grid 4 Grid 5 Grid 6 57.5 M4 59.4 M4 57.8 M4 Grid 7 Grid 8 Grid 9 82.4 M3 87.5 M3 86.7 M3



 $0 \, dB = 87.5 \, V/m$



Date/Time: 4/7/2010 2:12:58 PM

File Name: HAC_E_Dipole_CDMA1880_one_eigth.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF E Dipole

Communication System: CDMA 1900 1/8th; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 34.9 V/m; Power Drift = 1.08 dB

Maximum value of Total (measured) = 34.1 V/m



Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 34.4 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 34.9 V/m; Power Drift = 1.08 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
29.0 M4	30.4 M4	30.0 M4
Grid 4	Grid 5	Grid 6
23.0 M4	22.9 M4	20.5 M4
Grid 7	Grid 8	Grid 9
33.6 M4	34.4 M4	34.2 M4



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Daoud Attayi	April 05-08, 2010	K15-2008-1004-40	LOAKC230C	vv

Date/Time: 4/7/2010 2:18:40 PM

File Name: HAC_E_Dipole_CW1880_PMF_CDMA.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF E Dipole

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 103.6 V/m; Power Drift = -0.376 dB Maximum value of Total (measured) = 89.8 V/m



Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 91.0 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 103.6 V/m; Power Drift = -0.376 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
84.2 M3	90.1 M3	88.8 M3
Grid 4	Grid 5	Grid 6
60.0 M4	63.1 M3	61.8 M4
Grid 7	Grid 8	Grid 9
86.1 M3	91.0 M3	89.7 M3



Date/Time: 4/7/2010 2:23:44 PM

File Name: HAC_E_Dipole_AM_1880_PMF_CDMA.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Program Name: HAC RF E Dipole

Communication System: 80% AM; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 61.8 V/m; Power Drift = -0.117 dB

Maximum value of Total (measured) = 53.7 V/m



E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 54.6 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 61.8 V/m; Power Drift = -0.117 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
49.6 M4	52.2 M4	51.7 M4
Grid 4	Grid 5	Grid 6
35.2 M4	37.2 M4	36.4 M4
Grid 7	Grid 8	Grid 9
51.0 M4	54.6 M4	54.0 M4



 $0 \, dB = 54.6 \, V/m$

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Daoud Attayi	April 05-08, 2010	K1S-2068-1004-46	L6ARCZ30C	W

Date/Time: 4/7/2010 4:14:31 PM

File Name: HAC_H_Dipole_CW835_20.00dBm.da4

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.496 A/m; Power Drift = -0.123 dB

Maximum value of Total (measured) = 0.469 A/m



Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.471 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.496 A/m; Power Drift = -0.123 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.418 M4	0.461 M4	0.453 M4
Grid 4	Grid 5	Grid 6
0.437 M4	0.471 M4	0.459 M4
Grid 7	Grid 8	Grid 9
0.438 M4	0.469 M4	0.457 M4

Peak H-field in A/m



 $^{0 \,} dB = 0.471 \, A/m$



Date/Time: 4/7/2010 4:02:09 PM

File Name: HAC_H_Dipole_CDMA835_.da4

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CDMA 800; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.359 A/m; Power Drift = -0.062 dB

Maximum value of Total (measured) = 0.337 A/m



Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.339 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.359 A/m; Power Drift = -0.062 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.304 M4	0.333 M4	0.327 M4
Grid 4	Grid 5	Grid 6
0.315 M4	0.339 M4	0.329 M4
Grid 7	Grid 8	Grid 9
0.315 M4	0.336 M4	0.326 M4

Peak H-field in A/m



 $^{0 \,} dB = 0.339 \, A/m$



Date/Time: 4/7/2010 3:57:29 PM

File Name: HAC_H_Dipole_CDMA835_one_eigth.da4

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CDMA 800; Frequency: 835 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x13x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.129 A/m; Power Drift = 1.13 dB

Maximum value of Total (measured) = 0.138 A/m



Dipole = 10mm/Hearing Aid Compatibility Test (41x121x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.140 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.129 A/m; Power Drift = 1.13 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1 Grid 2 Grid 3 0.109 M4 0.138 M4 0.134 M4 Grid 4 Grid 5 Grid 6 0.140 M4 0.116 M4 0.136 M4 Grid 7 Grid 8 Grid 9 0.114 M4 0.132 M4 0.127 M4

Peak H-field in A/m



 $0 \ dB = 0.140 A/m$

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Daoud Attayi	April 05-08, 2010	RTS-2068-1004-46	L6ARCZ30C	W

Date/Time: 4/7/2010 4:06:06 PM

File Name: <u>HAC_H_Dipole_CW835_PMF_CDMA.da4</u>

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.354 A/m; Power Drift = -0.126 dB

Maximum value of Total (measured) = 0.331 A/m



Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.333 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.354 A/m; Power Drift = -0.126 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.300 M4	0.325 M4	0.317 M4
Grid 4	Grid 5	Grid 6
0.311 M4	0.333 M4	0.323 M4
Grid 7	Grid 8	Grid 9
0.311 M4	0.329 M4	0.322 M4



 $^{0 \} dB = 0.333 \text{A/m}$



Date/Time: 4/7/2010 4:10:40 PM

File Name: <u>HAC_H_Dipole_AM835_PMF_CDMA.da4</u>

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: 80% AM; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x13x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.224 A/m; Power Drift = 0.067 dB

Maximum value of Total (measured) = 0.212 A/m



Dipole = 10mm/Hearing Aid Compatibility Test (41x121x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.213 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.224 A/m; Power Drift = 0.067 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.189 M4	0.208 M4	0.204 M4
Grid 4	Grid 5	Grid 6
0.197 M4	0.213 M4	0.207 M4
Grid 7	Grid 8	Grid 9
0.197 M4	0.212 M4	0.206 M4

Peak H-field in A/m



 $^{0 \} dB = 0.213 \text{A/m}$



Date/Time: 4/7/2010 3:33:43 PM

File Name: <u>HAC_H_Dipole_CDMA1732.da4</u>

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CDMA AWS 1700; Frequency: 1732.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.361 A/m; Power Drift = 0.120 dB

Maximum value of Total (measured) = 0.343 A/m


dx=5mm, dy=5mm

Maximum value of peak Total field = 0.345 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.361 A/m; Power Drift = 0.120 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.299 M3	0.330 M3	0.322 M3
Grid 4	Grid 5	Grid 6
0.314 M3	0.345 M2	0.333 M3
Grid 7	Grid 8	Grid 9
0.302 M3	0.328 M3	0.319 M3



 $^{0 \,} dB = 0.345 \, A/m$

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Daoud Attayi	April 05-08, 2010 RTS-2068-1004-46 L6ARCZ30C		W	

Date/Time: 4/7/2010 3:43:10 PM

File Name: HAC_H_Dipole_CDMA1732_one_eigth.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CDMA AWS 1700_1/8th; Frequency: 1732.5 MHz;Duty Cycle:

1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.142 A/m; Power Drift = 0.103 dB

Maximum value of Total (measured) = 0.132 A/m



H Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.133 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.142 A/m; Power Drift = 0.103 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.113 M4	0.127 M4	0.121 M4
Grid 4	Grid 5	Grid 6
0.118 M4	0.133 M4	0.127 M4
Grid 7	Grid 8	Grid 9
0.113 M4	0.128 M4	0.122 M4



 $^{0 \,} dB = 0.133 \text{A/m}$

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Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	April 05-08, 2010 RTS-2068-1004-46 L6ARCZ30C		W	

Date/Time: 4/7/2010 2:55:37 PM

File Name: HAC_H_Dipole_CW1732_PMF_CDMA.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CW; Frequency: 1732 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.352 A/m; Power Drift = -0.062 dB

Maximum value of Total (measured) = 0.339 A/m



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.341 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.352 A/m; Power Drift = -0.062 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.288 M3	0.326 M3	0.314 M3
Grid 4	Grid 5	Grid 6
0.303 M3	0.341 M2	0.327 M3
Grid 7	Grid 8	Grid 9
0.293 M3	0.325 M3	0.313 M3



 $^{0 \,} dB = 0.341 \text{A/m}$



Date/Time: 4/7/2010 3:05:43 PM

File Name: HAC_H_Dipole_AM1732_PMF_CDMA.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: AM 80%; Frequency: 1732 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.221 A/m; Power Drift = 0.127 dB Maximum value of Total (measured) = 0.209 A/m



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.211 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.221 A/m; Power Drift = 0.127 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.181 M4	0.202 M3	0.196 M3
Grid 4	Grid 5	Grid 6
0.191 M3	0.211 M3	0.206 M3
Grid 7	Grid 8	Grid 9
0.185 M4	0.203 M3	0.197 M3



 $0 \, dB = 0.211 \, A/m$



Date/Time: 4/7/2010 2:42:18 PM

File Name: HAC_H_Dipole_CW1880_20.00dBm.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.476 A/m; Power Drift = -0.041 dB Maximum value of Total (measured) = 0.448 A/m



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.449 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.476 A/m; Power Drift = -0.041 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.402 M2	0.430 M2	0.422 M2
Grid 4	Grid 5	Grid 6
0.421 M2	0.449 M2	0.435 M2
Grid 7	Grid 8	Grid 9
0.405 M2	0.433 M2	0.420 M2



 $^{0 \,} dB = 0.449 \, A/m$



Date/Time: 4/7/2010 3:12:02 PM

File Name: <u>HAC_H_Dipole_CDMA1880.da4</u>

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.337 A/m; Power Drift = 0.067 dB Maximum value of Total (measured) = 0.314 A/m



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.316 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.337 A/m; Power Drift = 0.067 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.283 M3	0.309 M3	0.301 M3
Grid 4	Grid 5	Grid 6
0.292 M3	0.316 M3	0.309 M3
Grid 7	Grid 8	Grid 9
0.286 M3	0.307 M3	0.297 M3



 $^{0 \,} dB = 0.316 \, A/m$

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Date/Time: 4/7/2010 3:27:39 PM

File Name: HAC_H_Dipole_CDMA1880_one_eigth.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.133 A/m; Power Drift = -0.078 dB

Maximum value of Total (measured) = 0.124 A/m



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.125 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.133 A/m; Power Drift = -0.078 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.107 M4	0.120 M4	0.114 M4
Grid 4	Grid 5	Grid 6
0.111 M4	0.125 M4	0.119 M4
Grid 7	Grid 8	Grid 9
0.107 M4	0.119 M4	0.114 M4



 $^{0 \,} dB = 0.125 \, A/m$

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Date/Time: 4/7/2010 2:46:26 PM

File Name: HAC_H_Dipole_CW1880_PMF_CDMA.da4

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.331 A/m; Power Drift = 0.085 dB

Maximum value of Total (measured) = 0.310 A/m



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.312 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.331 A/m; Power Drift = 0.085 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1 Grid 2 Grid 3 0.280 M3 0.303 M3 0.300 M3 Grid 4 Grid 5 Grid 6 0.290 M3 0.312 M3 0.308 M3 Grid 7 Grid 8 Grid 9 0.283 M3 0.304 M3 0.299 M3



 $0 \, dB = 0.312 \text{A/m}$



Date/Time: 4/7/2010 2:51:09 PM

File Name: <u>HAC_H_Dipole_AM1880_PMF_CDMA.da4</u>

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Program Name: HAC RF H3DV6 Dipole

Communication System: AM 80%; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.205 A/m; Power Drift = 0.094 dB Maximum value of Total (measured) = 0.195 A/m



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.196 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.205 A/m; Power Drift = 0.094 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.179 M4	0.190 M3	0.187 M4
Grid 4	Grid 5	Grid 6
0.184 M4	0.196 M3	0.192 M3
Grid 7	Grid 8	Grid 9
0.174 M4	0.190 M4	0.184 M4



 $^{0 \} dB = 0.196 \text{A/m}$

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Justification of Step Size and Interpolation

This section demonstrates that a 5mm step size with interpolation provides sufficient resolution for RF emissions measurements. The DASY 4 uses interpolation algorithms to derive 9 interpolated points between every measured point.



The figure above shows the raw measured field strength perpendicular to the length of the validation dipole. The TCB guidance slides require the 3dB width to be much larger than the step size. The width between -3dB points is > 21mm, at least 4 times the step size.



This figure shows the interpolated field strength perpendicular to the dipole. The interpolated points follow the raw points with no inconsistencies.

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The green line in this figure shows the axis along which the points lie.

Comparison of 5mm and 2mm step sizes

An additional set of measurements was taken: dipole validations were performed using 5mm and 2mm step sizes. The delta between the two readings is insignificant for both field types (< 0.4% for E and 0% for H), demonstrating that 5mm is sufficient. The plots follow.



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Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: H Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of Total (measured) = 134.8 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of Total field (slot averaged) = 131.0 V/m

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

E in V/m (Time averaged) E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
123.2	138.1	138.4	123.2	138.1	138.4
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
80.9	92.3	92.2	80.9	92.3	92.2
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
110.8	131.0	130.7	119.8	131.0	130.7

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
		1	

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Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_2mm step_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: H Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1): Measurement grid: dx=2mm, dy=2mm

Maximum value of Total (measured) = 138.0 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1): Measurement grid: dx=2mm, dy=2mm Maximum value of Total field (slot averaged) = 131.2 V/m

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

E in V/m (Time averaged) E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
123.1	138.6	138.6	123.1	138.6	138.6
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
		-			
81.4	92.1	91.6	81.4	92.1	91.6
81.4 Grid 7	92.1 Grid 8	91.6 Grid 9	81.4 Grid 7	92.1 Grid 8	91.6 Grid 9

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_5 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Dipole Section

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of Total field (slot averaged) = 0.406 A/m Hearing Aid Near-Field Category: M2 (AWF 0 dB)

H in A/m (Time averaged) H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
0.342	0.359	0.344	0.342	0.359	0.344
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
0.389	0.406	0.389	0.389	0.406	0.389
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
0.363	0.378	0.363	0.363	0.378	0.363

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_2 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Dipole Section

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1):

Measurement grid: dx=2mm, dy=2mm Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):

Measurement grid: dx=2mm, dy=2mm Maximum value of Total field (slot averaged) = 0.406 A/m

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

H in A/m (Time averaged) H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
0.347	0.361	0.348	0.347	0.361	0.348
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
0.394	0.406	0.391	0.394	0.406	0.391
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
0.367	0.380	0.365	0.367	0.380	0.365

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_800_low chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA 800; Frequency: 824.7 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 101.6 V/m; Power Drift = -0.027 dB

Maximum value of Total (measured) = 77.6 V/m



Maximum value of peak Total field = 77.9 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 101.6 V/m; Power Drift = -0.027 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
69.8 M4	76.2 M4	74.1 M4
Grid 4	Grid 5	Grid 6
70.5 M4	77.9 M4	75.9 M4
Grid 7	Grid 8	Grid 9
68.7 M4	76.3 M4	74.1 M4







Date/Time: 4/7/2010 6:13:54 PM

Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_800_mid chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA 800; Frequency: 836.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 109.6 V/m; Power Drift = 0.133 dB

Maximum value of Total (measured) = 86.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 86.3 V/m

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Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 109.6 V/m; Power Drift = 0.133 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
72.9 M4	84.0 M4	83.2 M4
Grid 4	Grid 5	Grid 6
74.2 M4	86.3 M4	85.2 M4
Grid 7	Grid 8	Grid 9
72.7 M4	85.0 M4	83.2 M4





Date/Time: 4/7/2010 6:22:49 PM

Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_800_high chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 114.3 V/m; Power Drift = -0.035 dB

Maximum value of Total (measured) = 88.8 V/m

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Maximum value of peak Total field = 89.1 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 114.3 V/m; Power Drift = -0.035 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
77.5 M4	87.4 M4	86.2 M4
Grid 4	Grid 5	Grid 6
76.5 M4	89.1 M4	87.4 M4
Grid 7	Grid 8	Grid 9
74.0 M4	86.1 M4	85.1 M4







Date/Time: 4/7/2010 6:36:43 PM

Test Laboratory: RIM TESTING SERVICES

HAC_E_CDMA_800_high chan_one_eigth

DUT: BlackBerry Smartphone

Communication System: CDMA 800 1/8 th; Frequency: 848.52 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 42.0 V/m; Power Drift = -0.011 dB Maximum value of Total (measured) = 36.5 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 79.2 V/m

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Probe Modulation Factor = 2.17

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 42.0 V/m; Power Drift = -0.011 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
67.1 M4	76.1 M4	69.0 M4
Grid 4	Grid 5	Grid 6
66.8 M4	79.2 M4	71.1 M4
Grid 7	Grid 8	Grid 9
61.8 M4	67.7 M4	66.8 M4

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Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_800_high chan_telecoil.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 112.5 V/m; Power Drift = 0.135 dB

Maximum value of Total (measured) = 87.8 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 87.8 V/m

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Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 112.5 V/m; Power Drift = 0.135 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
76.5 M4	83.7 M4	81.6 M4
Grid 4	Grid 5	Grid 6
76.7 M4	87.8 M4	86.2 M4
Grid 7	Grid 8	Grid 9
77.1 M4	87.9 M4	86.4 M4





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Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_1700_low chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA AWS 1700; Frequency: 1711.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 48.2 V/m; Power Drift = 0.053 dB

Maximum value of Total (measured) = 43.1 V/m

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Maximum value of peak Total field = 41.3 V/m

Probe Modulation Factor = 0.970

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 48.2 V/m; Power Drift = 0.053 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
32.8 M4	41.9 M4	41.5 M4
Grid 4	Grid 5	Grid 6
30.4 M4	41.3 M4	41.2 M4
Grid 7	Grid 8	Grid 9
28.1 M4	34.3 M4	34.3 M4

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Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_1700_mid chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA AWS 1700; Frequency: 1732.5 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 56.8 V/m; Power Drift = -0.154 dB

Maximum value of Total (measured) = 51.1 V/m

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Maximum value of peak Total field = 49.2 V/m

Probe Modulation Factor = 0.970

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 56.8 V/m; Power Drift = -0.154 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
37.0 M4	49.8 M4	49.7 M4
Grid 4	Grid 5	Grid 6
34.0 M4	49.2 M4	49.1 M4
Grid 7	Grid 8	Grid 9
32.6 M4	40.3 M4	40.3 M4

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Date/Time: 4/7/2010 7:53:12 PM

Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_1700_high chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA AWS 1700; Frequency: 1732.5 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 46.8 V/m; Power Drift = -0.062 dB

Maximum value of Total (measured) = 43.6 V/m

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Maximum value of peak Total field = 41.4 V/m

Probe Modulation Factor = 0.970

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 46.8 V/m; Power Drift = -0.062 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
32.5 M4	42.7 M4	42.7 M4
Grid 4	Grid 5	Grid 6
28.8 M4	41.4 M4	41.4 M4
Grid 7	Grid 8	Grid 9
30.3 M4	32.4 M4	32.5 M4

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Test Laboratory: RIM TESTING SERVICES

File Name: HAC_E_CDMA_1700_mid chan_one_eigth.da4

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA AWS 1700_1/8th; Frequency: 1732.5 MHz;Duty Cycle:

1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 21.7 V/m; Power Drift = -1.04 dB Maximum value of Total (measured) = 20.0 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

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Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 50.3 V/m

Probe Modulation Factor = 2.58

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 21.7 V/m; Power Drift = -1.04 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
37.9 M4	51.6 M4	51.6 M4
Grid 4	Grid 5	Grid 6
32.0 M4	50.3 M4	50.1 M4
Grid 7	Grid 8	Grid 9
32.0 M4	40.3 M4	39.8 M4





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Test Laboratory: RIM TESTING SERVICES

File Name: HAC_E_CDMA_1700_mid chan_one_eigth_telecoil.da4

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA AWS 1700_1/8th; Frequency: 1732.5 MHz;Duty Cycle:

1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186
- E Scan ER3D 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 19.4 V/m; Power Drift = 1.08 dB Maximum value of Total (measured) = 20.0 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

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Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 50.5 V/m

Probe Modulation Factor = 2.58

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 19.4 V/m; Power Drift = 1.08 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
37.4 M4	49.3 M4	45.6 M4
Grid 4	Grid 5	Grid 6
36.8 M4	50.5 M4	51.6 M4
Grid 7	Grid 8	Grid 9





Date/Time: 4/7/2010 9:13:04 PM

Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_1900_low chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 49.0 V/m; Power Drift = -0.013 dB

Maximum value of Total (measured) = 49.0 V/m

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Maximum value of peak Total field = 49.1 V/m

Probe Modulation Factor = 1.04

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 49.0 V/m; Power Drift = -0.013 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
37.1 M4	51.3 M4	51.3 M4
Grid 4	Grid 5	Grid 6
32.6 M4	49.1 M4	49.0 M4
Grid 7	Grid 8	Grid 9
34.9 M4	37.4 M4	37.4 M4

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Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_1900_mid chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 44.4 V/m; Power Drift = 0.084 dB

Maximum value of Total (measured) = 47.0 V/m

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Maximum value of peak Total field = 46.4 V/m

Probe Modulation Factor = 1.04

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 44.4 V/m; Power Drift = 0.084 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
34.1 M4	49.2 M4	49.2 M4
Grid 4	Grid 5	Grid 6
29.2 M4	46.4 M4	46.5 M4
Grid 7	Grid 8	Grid 9
35.2 M4	35.3 M4	35.9 M4

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Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_1900_high chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA 1900; Frequency: 1908.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 50.4 V/m; Power Drift = -0.076 dB

Maximum value of Total (measured) = 51.8 V/m

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Daoud Attayi	April 05-08, 2010	RTS-2068-1004-46	L6ARCZ30C	W

Maximum value of peak Total field = 51.6 V/m

Probe Modulation Factor = 1.04

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 50.4 V/m; Power Drift = -0.076 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
39.5 M4	54.5 M4	54.4 M4
Grid 4	Grid 5	Grid 6
34.1 M4	51.6 M4	51.6 M4
Grid 7	Grid 8	Grid 9
37.8 M4	38.8 M4	38.9 M4

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Date/Time: 4/7/2010 9:45:23 PM

Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_E_CDMA_1900_high chan_one_eigth.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA 1900 1/8th; Frequency: 1908.5 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 17.3 V/m; Power Drift = 0.078 dB

Maximum value of Total (measured) = 20.4 V/m

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Daoud Attayi	April 05-08, 2010	RTS-2068-1004-46	L6ARCZ30C	W

Maximum value of peak Total field = 45.6 V/m

Probe Modulation Factor = 2.65

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 17.3 V/m; Power Drift = 0.078 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
37.5 M4	54.1 M4	48.8 M4
Grid 4	Grid 5	Grid 6
29.7 M4	45.6 M4	45.4 M4
Grid 7	Grid 8	Grid 9
37.9 M4	34.9 M4	35.0 M4

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Date/Time: 4/7/2010 9:56:35 PM

Test Laboratory: RIM TESTING SERVICES

File Name: HAC_E_CDMA_1900_high chan_telecoil.da4

DUT: BlackBerry Smartphone

Program Name: HAC RF ER3D Device

Communication System: CDMA 1900; Frequency: 1908.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/8/2010

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 49.4 V/m; Power Drift = -0.017 dB

Maximum value of Total (measured) = 51.9 V/m

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Maximum value of peak Total field = 53.8 V/m

Probe Modulation Factor = 1.04

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 49.4 V/m; Power Drift = -0.017 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
41.4 M4	54.0 M4	53.3 M4
Grid 4	Grid 5	Grid 6
40.3 M4	53.8 M4	53.0 M4
Grid 7	Grid 8	Grid 9
31.2 M4	45.2 M4	44.9 M4

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Date/Time: 4/7/2010 10:39:33 PM

Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_H_CDMA800_low_chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: CDMA 800; Frequency: 824.7 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.081 A/m; Power Drift = 0.058 dB Maximum value of Total (measured) = 0.151 A/m



Maximum value of peak Total field = 0.102 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.081 A/m; Power Drift = 0.058 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.147 M4	0.101 M4	0.061 M4
Grid 4	Grid 5	Grid 6
0.139 M4	0.097 M4	0.058 M4
Grid 7	Grid 8	Grid 9
0.148 M4	0.102 M4	0.059 M4



 $0 \ dB = 0.148 \text{A/m}$



Date/Time: 4/7/2010 10:55:38 PM

Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_H_CDMA800_mid_chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: CDMA 800; Frequency: 836.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.089 A/m; Power Drift = 0.042 dB Maximum value of Total (measured) = 0.164 A/m



Maximum value of peak Total field = 0.114 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.089 A/m; Power Drift = 0.042 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.161 M4	0.114 M4	0.073 M4
Grid 4	Grid 5	Grid 6
0.149 M4	0.107 M4	0.066 M4
Grid 7	Grid 8	Grid 9
0.161 M4	0.112 M4	0.063 M4





Date/Time: 4/7/2010 11:05:40 PM

Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_H_CDMA800_high_chan.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.107 A/m; Power Drift = 0.125 dB Maximum value of Total (measured) = 0.185 A/m

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Maximum value of peak Total field = 0.134 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.107 A/m; Power Drift = 0.125 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.170 M4	0.123 M4	0.079 M4
Grid 4	Grid 5	Grid 6
0.169 M4	0.126 M4	0.083 M4
Grid 7	Grid 8	Grid 9
0.181 M4	0.134 M4	0.086 M4

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Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_H_CDMA800_high_chan_one_eigth.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: CDMA 800 1/8 th; Frequency: 848.52 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.039 A/m; Power Drift = 0.022 dB Maximum value of Total (measured) = 0.074 A/m

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H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
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Maximum value of peak Total field = 0.123 A/m

Probe Modulation Factor = 2.38

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.039 A/m; Power Drift = 0.022 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.154 M4	0.120 M4	0.078 M4
Grid 4	Grid 5	Grid 6
0.163 M4	0.121 M4	0.078 M4
Grid 7	Grid 8	Grid 9
0.177 M4	0.123 M4	0.080 M4

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Date/Time: 4/7/2010 11:24:28 PM

Test Laboratory: RIM TESTING SERVICES

File Name: <u>HAC_H_CDMA800_high_chan_telecoil.da4</u>

DUT: BlackBerry Smartphone

Program Name: HAC RF H3DV6 Device

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn473; Calibrated: 1/4/2010

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.109 A/m; Power Drift = -0.053 dB Maximum value of Total (measured) = 0.180 A/m

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Maximum value of peak Total field = 0.131 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.109 A/m; Power Drift = -0.053 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.173 M4	0.125 M4	0.080 M4
Grid 4	Grid 5	Grid 6
0.171 M4	0.124 M4	0.081 M4
Grid 7	Grid 8	Grid 9
0.177 M4	0.131 M4	0.085 M4



 $0 \ dB = 0.177 \mbox{A/m}$



Date/Time: 4/7/2010 11:44:18 PM

Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1700_low_chan

DUT: BlackBerry Smartphone

Communication System: CDMA AWS 1700; Frequency: 1711.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.108 A/m; Power Drift = 0.038 dB Maximum value of Total (measured) = 0.126 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.117 A/m

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Probe Modulation Factor = 0.990

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.108 A/m; Power Drift = 0.038 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.117 M4	0.103 M4	0.077 M4
Grid 4	Grid 5	Grid 6
0.113 M4	0.111 M4	0.092 M4
Grid 7	Grid 8	Grid 9
0.124 M4	0.119 M4	0.097 M4

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Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1700_mid_chan

DUT: BlackBerry Smartphone

Communication System: CDMA AWS 1700; Frequency: 1732.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.125 A/m; Power Drift = 0.011 dB Maximum value of Total (measured) = 0.137 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.134 A/m

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Probe Modulation Factor = 0.990

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.125 A/m; Power Drift = 0.011 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.134 M4	0.118 M4	0.089 M4
Grid 4	Grid 5	Grid 6
0.126 M4	0.125 M4	0.106 M4
Grid 7	Grid 8	Grid 9
0.135 M4	0.134 M4	0.111 M4

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Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1700_high_chan

DUT: BlackBerry Smartphone

Communication System: CDMA AWS 1700; Frequency: 1753.75 MHz;Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.111 A/m; Power Drift = 0.143 dB Maximum value of Total (measured) = 0.120 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.111 A/m

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Probe Modulation Factor = 0.990

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.111 A/m; Power Drift = 0.143 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.118 M4	0.104 M4	0.084 M4
Grid 4	Grid 5	Grid 6
0.107 M4	0.107 M4	0.097 M4
Grid 7	Grid 8	Grid 9
0.112 M4	0.111 M4	0.099 M4

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Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1700_mid_chan_one_eigth

DUT: BlackBerry Smartphone

Communication System: CDMA AWS 1700_1/8th; Frequency: 1732.5 MHz;Duty Cycle:

1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.045 A/m; Power Drift = -0.040 dB Maximum value of Total (measured) = 0.055 A/m



Maximum value of peak Total field = 0.123 A/m

Probe Modulation Factor = 2.56

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.045 A/m; Power Drift = -0.040 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.140 M4	0.123 M4	0.086 M4
Grid 4	Grid 5	Grid 6
0.130 M4	0.122 M4	0.101 M4
Grid 7	Grid 8	Grid 9

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Date/Time: 4/8/2010 12:40:34 AM

Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1700_mid_chan_telecoil

DUT: BlackBerry Smartphone

Communication System: CDMA AWS 1700; Frequency: 1732.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.124 A/m; Power Drift = 0.019 dB Maximum value of Total (measured) = 0.136 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.128 A/m

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Testing Services ^{**}	Document Annex A_Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RCZ31CW			

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.124 A/m; Power Drift = 0.019 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.135 M4	0.117 M4	0.081 M4
Grid 4	Grid 5	Grid 6
0.130 M4	0.120 M4	0.098 M4
Grid 7	Grid 8	Grid 9
0.129 M4	0.128 M4	0.109 M4

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Date/Time: 4/8/2010 12:57:28 AM

Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1900_low_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.112 A/m; Power Drift = 0.140 dB Maximum value of Total (measured) = 0.137 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.109 A/m

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Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.112 A/m; Power Drift = 0.140 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.135 M4	0.116 M4	0.081 M4
Grid 4	Grid 5	Grid 6
0.115 M4	0.109 M4	0.095 M4
Grid 7	Grid 8	Grid 9
0.109 M4	0.109 M4	0.097 M4

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Date/Time: 4/8/2010 1:21:20 AM

Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1900_mid_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.118 A/m; Power Drift = 0.042 dB Maximum value of Total (measured) = 0.130 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.113 A/m

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Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.118 A/m; Power Drift = 0.042 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.129 M4	0.116 M4	0.088 M4
Grid 4	Grid 5	Grid 6
0.113 M4	0.111 M4	0.102 M4
Grid 7	Grid 8	Grid 9
0.112 M4	0.113 M4	0.103 M4

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Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1900_high_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1908.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.133 A/m; Power Drift = -0.038 dB Maximum value of Total (measured) = 0.151 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.128 A/m

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Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.133 A/m; Power Drift = -0.038 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.149 M4	0.131 M4	0.099 M4
Grid 4	Grid 5	Grid 6
0.130 M4	0.128 M4	0.113 M4
Grid 7	Grid 8	Grid 9
0.127 M4	0.128 M4	0.114 M4

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Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1900_high_chan_one_eigth

DUT: BlackBerry Smartphone

Communication System: CDMA 1900 1/8th; Frequency: 1908.5 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.047 A/m; Power Drift = 0.018 dB Maximum value of Total (measured) = 0.058 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.125 A/m

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Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.047 A/m; Power Drift = 0.018 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.144 M4	0.117 M4	0.090 M4
Grid 4	Grid 5	Grid 6
0.130 M4	0.125 M4	0.110 M4
Grid 7	Grid 8	Grid 9
0.131 M4	0.123 M4	0.114 M4

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Test Laboratory: RIM TESTING SERVICES

HAC_H_CDMA1900_high_chan_one_eigth_telecoil

DUT: BlackBerry Smartphone

Communication System: CDMA 1900 1/8th; Frequency: 1908.5 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/13/2009
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/4/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.047 A/m; Power Drift = 1.16 dB Maximum value of Total (measured) = 0.060 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.127 A/m

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Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.047 A/m; Power Drift = 1.16 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.150 M4	0.124 M4	0.080 M4
Grid 4	Grid 5	Grid 6
0.140 M4	0.123 M4	0.095 M4
Grid 7	Grid 8	Grid 9
0.128 M4	0.127 M4	0.108 M4

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